Supporting Information

Local Structure Distortion Induced by Ti dopant Boosting

the Pseudocapacitance of RuO₂-Based Supercapacitors

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This supporting information includes 6 figures and 1 table.



Figure S1 XRD patterns for CRT91-As, CRT73-As, and CRT55-As. The diffraction features of rutile RuO₂ (JCPDS #43-1027) and TiO₂ (JCPDS #21-1276) are provided for a comparison purpose.



Figure S2 XANES spectra at the Ru *K*-edge for anhydrous RuO₂, metallic Ru, CRT91-As, CRT73-As, and CRT55-As. All spectra presented here are normalized to the same scale for comparison.



Figure S3 A series of k^3 -weighted Fourier-transformed EXAFS functions at the Ru *K*-edge with their corresponding fits for RuO₂ together with different Ru-Ti atomic ratios oxides treated at 200°C condition. All spectra presented here are normalized to the same scale (see the multiple factor number) for a clear comparison purpose.



Figure S4 Representative electron diffraction (ED) patterns for three Ru-Ti oxides.



Figure S5 CV curves measured in 0.5 M H_2SO_4 at 25 mV s⁻¹ for CR-As, CRT91-As, CRT73-As, and CRT55-As samples.

Table S1 A comparison of the total specific capacitance and specific capacitance based on RuO_2 for $RuO_2 \cdot nH_2O$ and Ru_x - $Ti_{1-x}O_2 \cdot nH_2O$ with and without the thermal treatment at 200°C.

Samples	CR	CRT91	CRT73	CRT55
As-prepared	311.0	358.7	503.1	534.6
Heat treatmenet at 200°C	569.0	739.1	793.7	655.0

Capacitive performance index of specific capacitance is estimated from the CV curves measured in 0.5 M $\rm H_2SO_4$ at 25 mV s^{-1}



Figure S6 The dependence of total specific capacitance $(C_{S,T})$ and the specific capacitance based on RuO₂ $(C_{S,RuO2})$ for various RuTi oxides on the TiO₂ content in the samples.